TOSHIBA Field Effect Transistor Silicon N Channel MOS Type (L^2 - π -MOSV)

2SK2789

Chopper Regulator, DC-DC Converter and Motor Drive Applications

• 4-V gate drive

• Low drain-source ON resistance : $R_{DS(ON)} = 66 \text{ m}\Omega \text{ (typ.)}$

• High forward transfer admittance : |Y_{fs}| = 16 S (typ.)

• Low leakage current : I_{DSS} = 100 μA (max) (V_{DS} = 100 V)

Enhancement mode : V_{th} = 0.8 to 2.0 V (V_{DS} = 10 V, I_D = 1 mA)

Absolute Maximum Ratings (Ta = 25°C)

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Characteristics			Symbol	Rating	Unit
Drain-source voltage			V_{DSS}	100	\\y
Drain-gate voltage (R _{GS} = 20 kΩ)			V_{DGR}	100	V
Gate-source voltage			V _{GSS}	±20	V
Drain current	DC	(Note 1)	ID	27	Α
	Pulse	(Note 1)	I _{DP}	108	A
Drain power dissipation (Tc = 25°C)			PD	60	<\\w\
Single pulse avalanche energy (Note 2)			EAS	193	mJ
Avalanche current			(TAR (27 〈	\ A
Repetitive avalanche energy (Note 3)			EAR	6	Juh
Channel temperature			√(ch	150	√°C
Storage temperature range			Tstg	-55 to 150	→°C

Note: Using continuously under heavy toads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions") "Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to case	R _{th (ch-c)}	2.08	°C/W
Thermal resistance, channel to ambient	R _{th (ch-a)}	83.3	°C/W

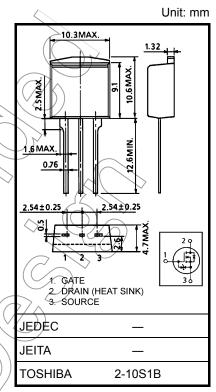
Note 1: Ensure that the channel temperature does not exceed 150°C.

Note 2: V_{DD} = 25 V, T_{ch} = 25°C (initial), L = 428 μ H, I_{AR} = 27 A, R_G = 25 Ω

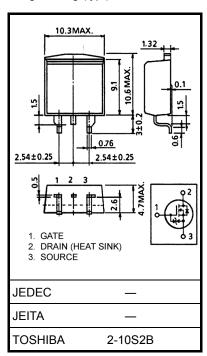
Note 3: Repetitive rating: pulse width limited by maximum channel temperature

This transistor is an electrostatic-sensitive device.

Please handle with caution.



Weight: 1.5 g (typ.)



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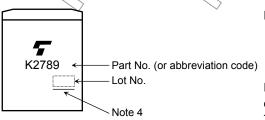
Electrical Characteristics (Ta = 25°C)

Charac	cteristics	Symbol	Test Condition	Min	Тур.	Max	Unit	
Gate leakage cu	rrent	I _{GSS}	V _{GS} = ±16 V, V _{DS} = 0 V	_	_	±10	μΑ	
Drain cut-off cu	rrent	I _{DSS}	V _{DS} = 100 V, V _{GS} = 0 V	_	_	100	μΑ	
Drain-source br	eakdown voltage	V (BR) DSS	I _D = 10 mA, V _{GS} = 0 V	100	_	_	V	
Gate threshold v	oltage	V _{th}	V _{DS} = 10 V, I _D = 1 mA	0.8	_	2.0	V	
Drain-source ON resistance		R _{DS (ON)}	V _{GS} = 4 V, I _D = 15 A	(F	0.09	0.13	- Ω	
			V _{GS} = 10 V, I _D = 15 A	> <u>~</u>	0.066	0.085		
Forward transfer	admittance	Y _{fs}	V _{DS} = 10 V, I _D = 15 A	<u>8</u>	16	_	S	
Input capacitance		C _{iss}		_	1100			
Reverse transfer capacitance		C _{rss}	V _{DS} = 10 V, V _{GS} = 0 V, f = 1 MHz	_	180		pF	
Output capacitance		Coss		_	400			
Switching time	Rise time	t _r	V_{GS}^{10V} $I_{D}=15A$ V_{OUT} $R_{L}=3.3\Omega$	- (20	\\ \rangle \ \rangle		
	Turn-on time	t _{on}			30) –		
	Fall time	t _f	W FOV		50	_	ns	
	Turn-off time	t _{off}	$V_{DD} = 50V$ Duty \(\frac{1}{3}, \text{t}_{\text{W}} = 10 \mu \text{s}		140	_		
Total gate charge (gate-source plus gate-drain)		Qg			50			
Gate-source charge		Q _{gs} ($V_{DD} \approx 80 \text{ V}, V_{GS} = 10 \text{ V}, V_{D} = 27 \text{ V}$	_	34	_	nC	
Gate-drain ("mil	ler") Charge	Q _{gd}		_	16	_		

Source-Drain Ratings and Characteristics (Ta = 25°C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Continuous drain reverse current (Note 1)	lor	<u> </u>	_	_	27	Α
Pulse drain reverse current (Note 1)	\ I _{DRP}	_	_	_	108	Α
Forward voltage (diode)	V_{DSF}	I _{DR} = 27 A, V _{GS} = 0 V	_	_	-1.7	V
Reverse recovery time	t _{rr}	I _{DR} = 27 A, V _{GS} = 0 V, dI _{DR} / dt = 50 A / μs		155		ns
Reverse recovery charge	Qrr	1DR - 27 A, VGS - 0 V, αDR / αι - 50 A / μS		0.31		μC

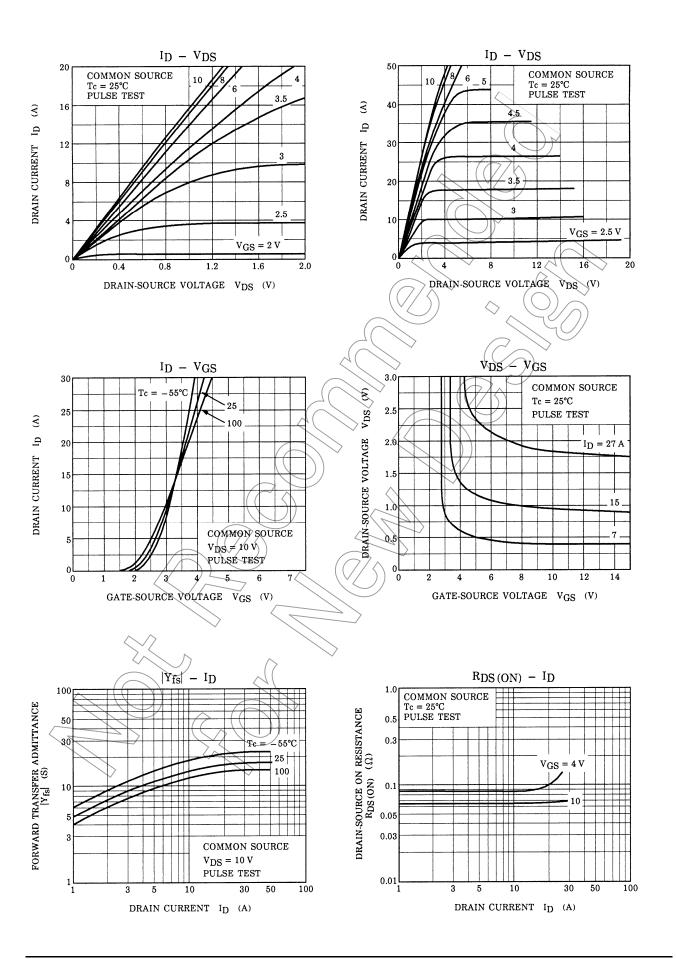




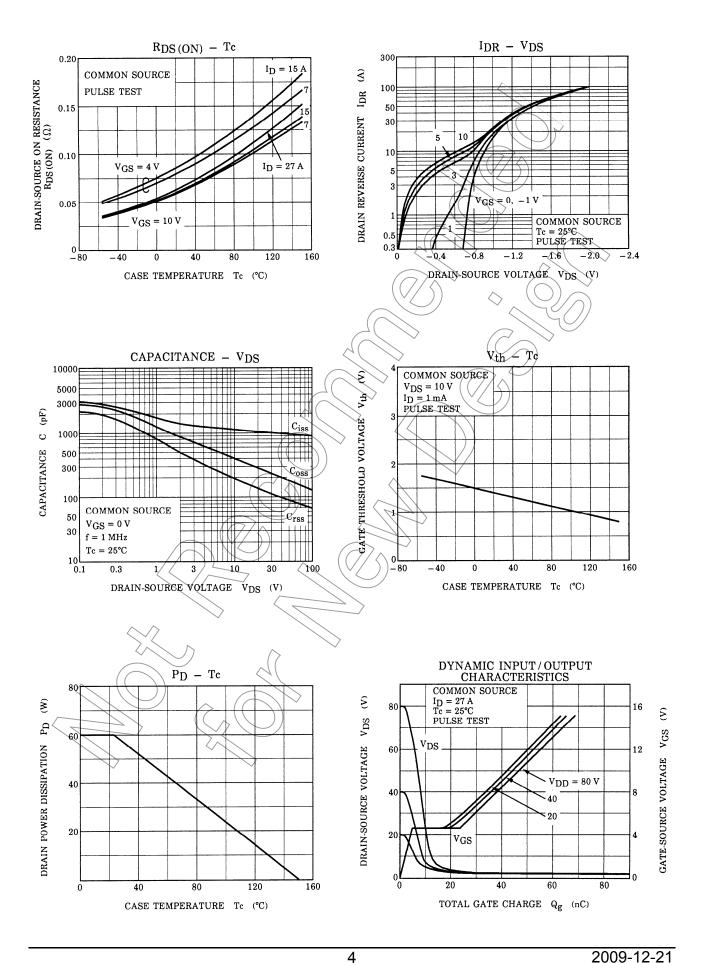
Note 4: A line under a Lot No. identifies the indication of product Labels.

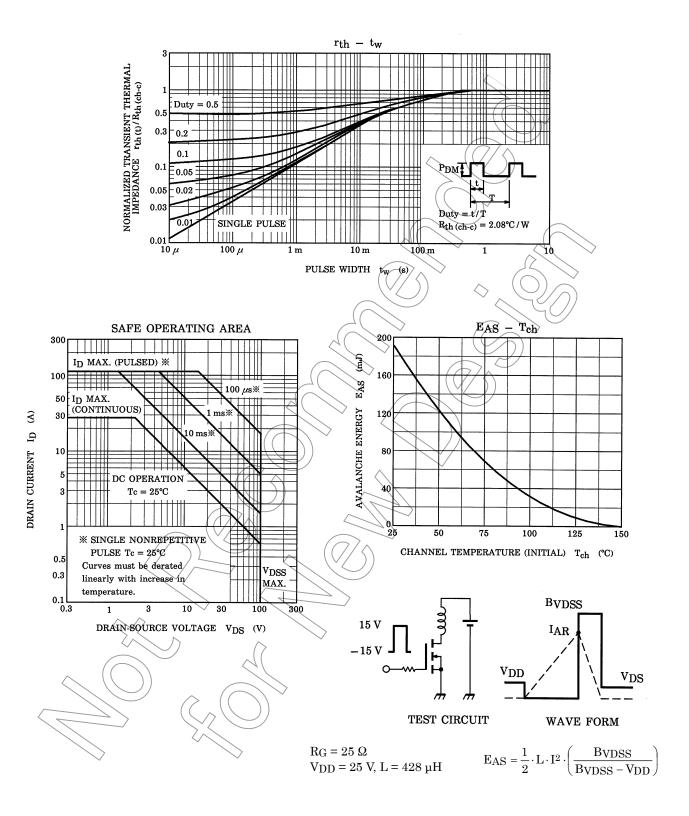
Not underlined: [[Pb]]/INCLUDES > MCV Underlined: [[G]]/RoHS COMPATIBLE or [[G]]/RoHS [[Pb]]

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